

MDS70

70 Watts, 50 Volts, Pulsed Avionics 1030 - 1090MHz

GENERAL DESCRIPTION

The MDS70 is a COMMON BASE bipolar transistor. It is designed for MODE S pulsed systems in the frequency band 1030-1090 MHz. The device has gold thin-film metallization for proven highest MTTF. The transistor includes input prematch for broadband capacity. Low thermal resistance package reduces junction temperature, extends life.

ABSOLUTE MAXIMUM RATINGS

Maximum Power Dissipation @ 25°C² 225 Watts

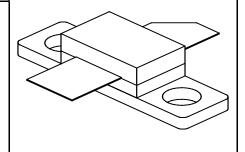
Maximum Voltage and Current

BVcesCollector to Base Voltage65 VoltsBVeboEmitter to Base Voltage3.5 VoltsIcCollector Current5.0 Amps

Maximum Temperatures

 $\begin{array}{ll} \mbox{Storage Temperature} & -65 \mbox{ to} + 150 \mbox{^{o}C} \\ \mbox{Operating Junction Temperature} & + 200 \mbox{^{o}C} \end{array}$

CASE OUTLINE 55CX, STYLE 1



ELECTRICAL CHARACTERISTICS @ 25 °C

SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Pout	Power Out	F = 1030-1090 MHz	70		95	Watts
Pg	Power Gain	Vcc = 50 Volts Pin = 6.5W	10.3		11.65	dB
RT	Rise Time	Pulse Mod: Mode S ²			80	ns
ης	Collector Efficiency	Pulse Mod: Mode S	35			%
VSWR ¹	Load Mismatch Tolerance	1090 MHz	5:1			

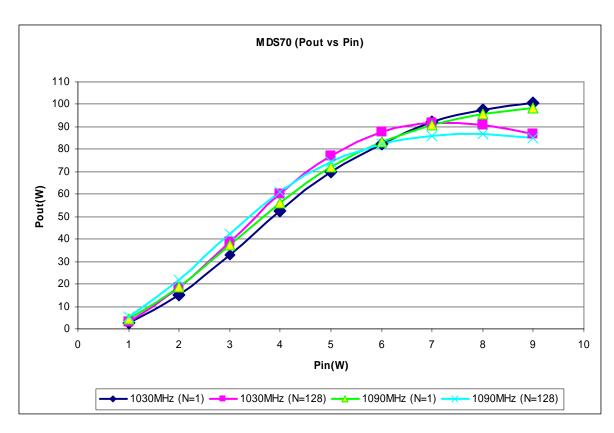
BVebo	Emitter to Base Breakdown	Ie = 5 mA	3.5		Volts
BVces	Collector to Emitter Breakdown	Ic = 25 mA	65		Volts
hFE	DC - Current Gain	Ic = 500 mA, Vce = 5 V	20		
θjc ¹	Thermal Resistance			0.8	°C/W

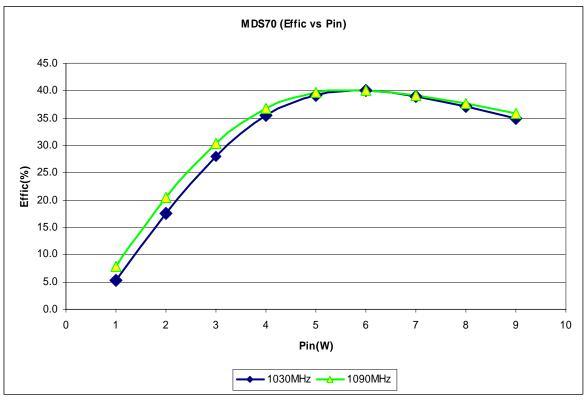
Notes: 1) At rated pulse conditions

2) Mode S Burst: 0.5us (on/off), N=128, Per=6.4ms; LTDC=1%

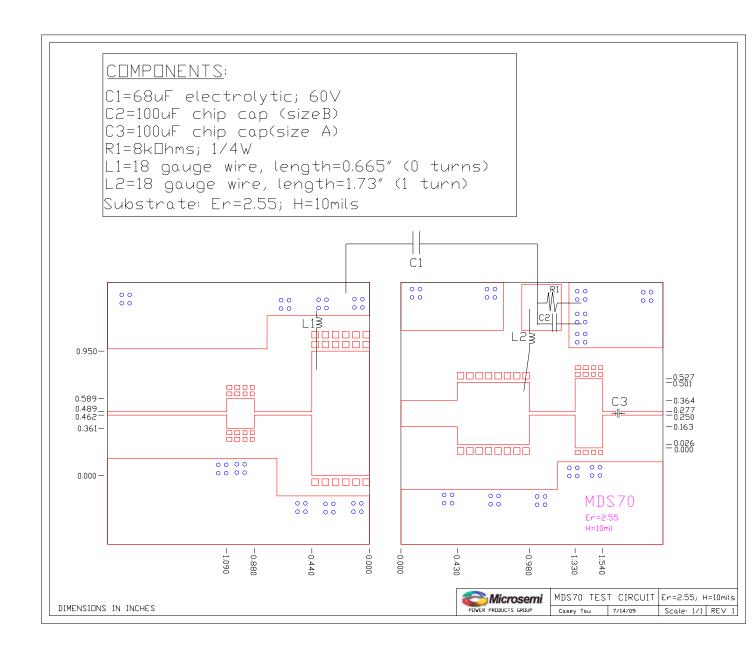
Rev C: August 2010

Microsemi reserves the right to change, without notice, the specifications and information contained herein. Visit our web site at www.microsemi.com or contact our factory direct.



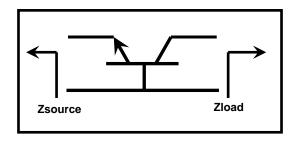


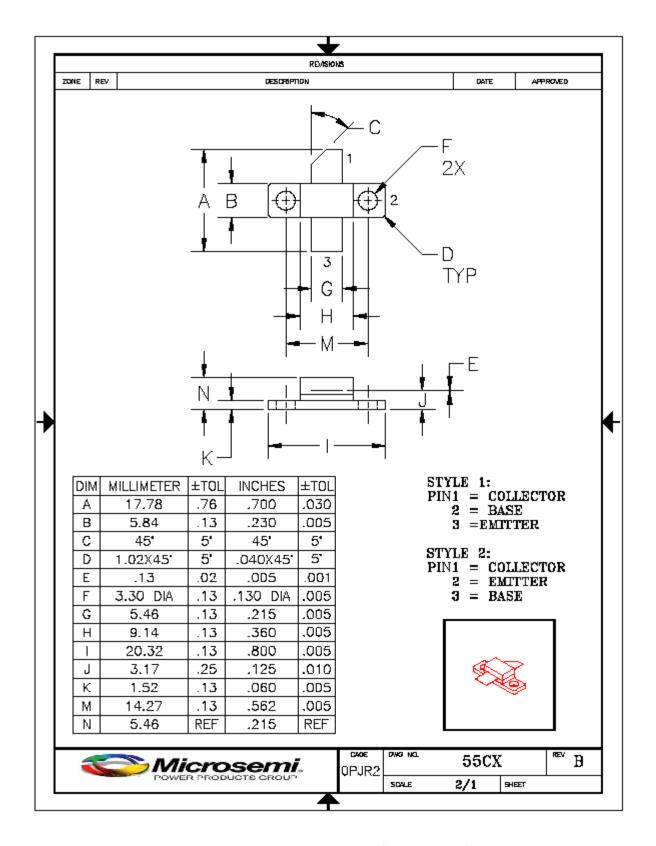
Microsemi reserves the right to change, without notice, the specifications and information contained herein. Visit our web site at www.microsemi.com or contact our factory direct.



MDS70 IMPEDANCE DATA:

FREQUENCY	Z _{source} (ohms)	Z _{load} (ohms)
1030	3.0 - j4.8	5.3 - j1.2
1090	2.8 - j4.5	6.2 - j1.2





Microsemi reserves the right to change, without notice, the specifications and information contained herein. Visit our web site at www.microsemi.com or contact our factory direct.